



Micro Commercial Components  
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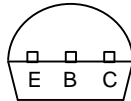
## 2SC2216

### Features

- Capable of 300mWatts of Power Dissipation.
- Collector-current 50mA
- Collector-base Voltage 50V
- Operating and storage junction temperature range: -55°C to +150°C

### NPN Silicon Plastic-Encapsulate Transistor

Pin Configuration  
Bottom View



### Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
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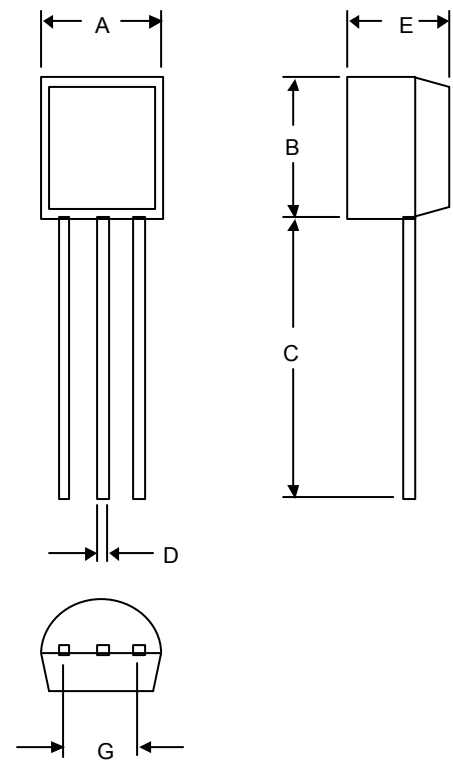
#### OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ( $I_C=10\text{mA}$ , $I_B=0$ )	45	---	Vdc
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ( $I_C=100\mu\text{A}$ , $I_E=0$ )	50	---	Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ( $I_E=100\mu\text{A}$ , $I_C=0$ )	4.0	---	Adc
$I_{CBO}$	Collector Cutoff Current ( $V_{CB}=50\text{Vdc}$ , $I_E=0$ )	---	0.1	$\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current ( $V_{EB}=4.0\text{Vdc}$ , $I_C=0$ )	---	0.1	$\mu\text{A}$

#### ON CHARACTERISTICS

$h_{FE}$	DC Current Gain ( $I_C=12.5\text{mA}$ , $V_{CE}=12.5\text{Vdc}$ )	40	140	---
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ( $I_C=15\text{mA}$ , $I_B=1.5\text{mA}$ )	---	0.2	Vdc
$V_{(BE)sat}$	Base-Emitter Saturation Voltage ( $I_C=15\text{mA}$ , $I_B=1.5\text{mA}$ )	---	1.5	Vdc
fT	Transition Frequency ( $V_{CE}=12.5\text{Vdc}$ , $I_C=12.5\text{mA}$ , f=100MHz)	300	---	MHz

### TO-92



#### DIMENSIONS

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.175	.185	4.45	4.70	
B	.175	.185	4.46	4.70	
C	.500	---	12.7	---	
D	.016	.020	0.41	0.63	
E	.135	.145	3.43	3.68	
G	.095	.105	2.42	2.67	